

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 10 \text{ A}$



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 40 A				
V _{RRM}	100 V				
I _{FSM}	450 A				
E _{AS} at L = 180 mH	700 mJ				
V _F at I _F = 40 A	0.64 V				
T _J max.	150 °C				

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses

• High efficiency operation

COMPLIANT HALOGEN

- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free and RoHS compliant,

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V80100PW	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	100	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	80	А	
	per diode		40		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	450	А	
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 180$ r	E _{AS}	700	mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	1.0	А	
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C	

V80100PW

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	-	V	
Instantaneous forward voltage per diode	I _F = 10 A	T _A = 25 °C	- V _F ⁽¹⁾	0.49	-		
	I _F = 20 A			0.59	-		
	I _F = 40 A			0.76	0.84		
	I _F = 10 A	T _J = 125 °C		0.43	-		
	I _F = 20 A			0.55	-		
	I _F = 40 A			0.64	0.76		
Reverse current per diode	V _R = 80 V	T _A = 25 °C	I _R ⁽²⁾	38	-	μΑ	
		T _A = 125 °C		17	-	mA	
	V _R = 100 V	T _A = 25 °C		85	1000	μΑ	
		T _A = 125 °C		33	76	mA	

Notes

 $^{(1)}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	V80100PW	UNIT		
Typical thermal resistance	per diode	- R _{θJC}	1.5	°C/W		
	per device		0.8			

ORDERING INFORMATION (Example)						
PACKAGE PREFERRED P/N U		UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	V80100PW-M3/4W	4.5	4W	30/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

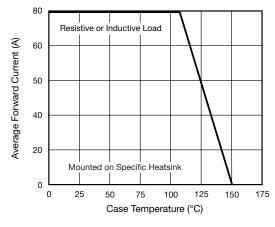


Fig. 1 - Forward Current Derating Curve

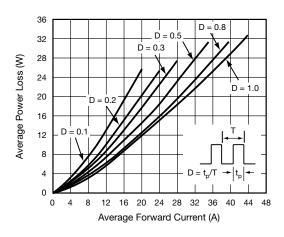


Fig. 2 - Forward Power Loss Characteristics Per Diode



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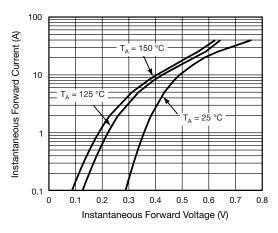


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

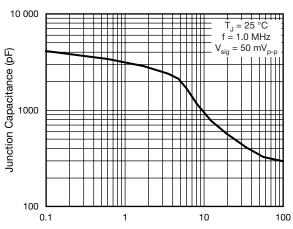


Fig. 5 - Typical Junction Capacitance Per Diode

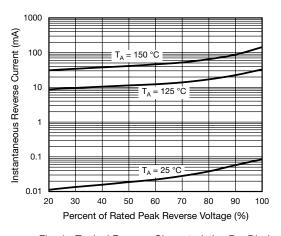


Fig. 4 - Typical Reverse Characteristics Per Diode

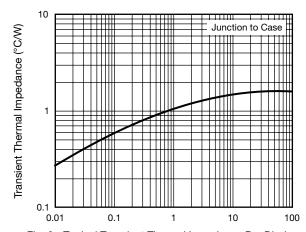
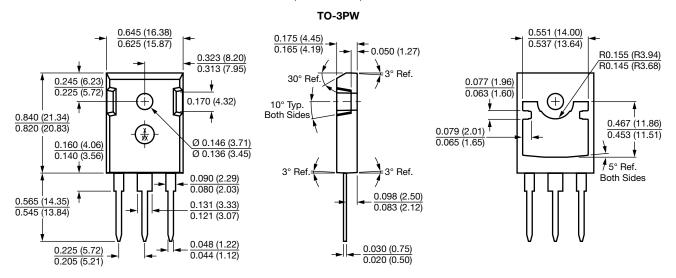


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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